2SD2000

Silicon NPN triple diffusion planar type

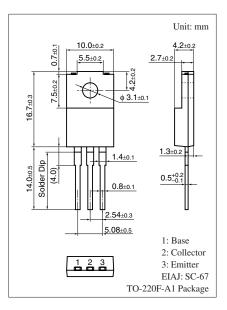
For power switching

Features

- High-speed switching
- \bullet Satisfactory linearity of forward current transfer ratio h_{FE}
- \bullet Large collector power dissipation $P_{\rm C}$
- Full-pack package which can be installed to the heat sink with one screw.

Parameter	Symbol	Rating	Unit				
Collector-base voltage (Er	V _{CBO}	80	V				
Collector-emitter voltage	V _{CEO}	60	V				
Emitter-base voltage (Col	V _{EBO}	6	V				
Collector current	I _C	4	А				
Peak collector current	I _{CP}	8	А				
Base current	IB	1	А				
Collector power		P _C	35	W			
dissipation	$T_a = 25^{\circ}C$		2.0				
Junction temperature		Tj	150	°C			
Storage temperature	T _{stg}	-55 to +150	°C				

Absolute Maximum Ratings $T_C = 25^{\circ}C$



Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 25 \text{ mA}, I_{\rm B} = 0$	60			V
Base-emitter voltage	V _{BE}	$V_{CE} = 4 V, I_C = 4 A$			2.0	V
Collector-base cut-off current (Emitter open)	I _{CBO}	$V_{CB} = 80 V, I_E = 0$			100	μΑ
Emitter-base cut-off current (Collector open)	I _{EBO}	$V_{EB} = 6 V, I_C = 0$			100	μΑ
Forward current transfer ratio	h _{FE1} *	$V_{CE} = 4 V, I_C = 1 A$	70		250	
	h _{FE2}	$V_{CE} = 4 V, I_C = 4 A$	20			
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 4 {\rm A}, I_{\rm B} = 0.4 {\rm A}$			1.5	V
Transition frequency	f _T	$V_{CE} = 12 \text{ V}, I_C = 0.2 \text{ A}, f = 10 \text{ MHz}$		80		MHz
Turn-on time	t _{on}	$I_C = 4 A, I_{B1} = 0.4 A, I_{B2} = -0.4 A,$		0.3		μs
Storage time	t _{stg}	$V_{\rm CC} = 50 \text{ V}$		1.0		μs
Fall time	t _f			0.2		μs

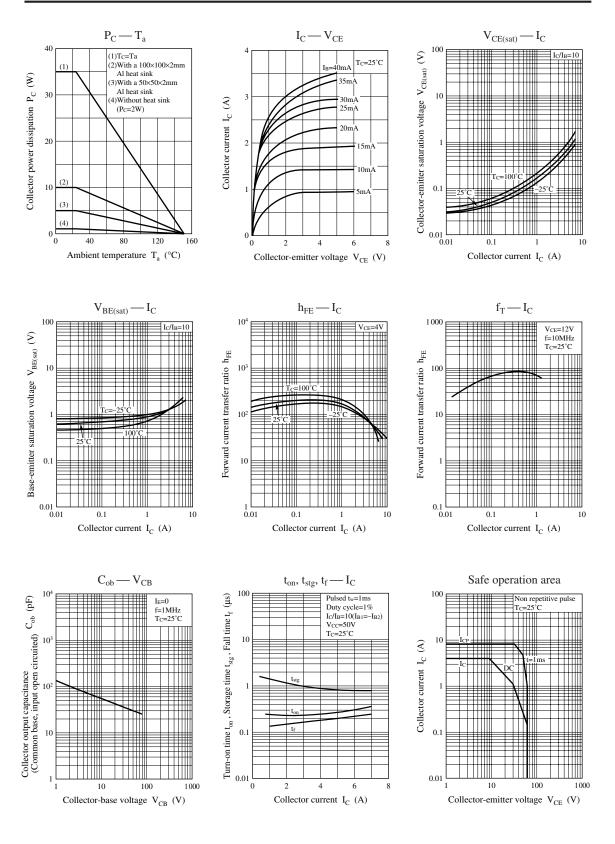
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

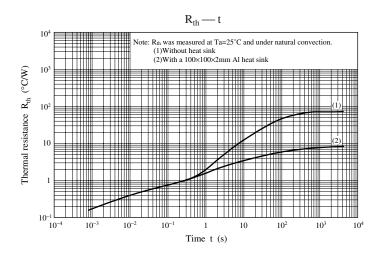
Rank	Q	Р		
h _{FE1}	70 to 150	120 to 250		

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